NSN 5962-01-505-1315

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Operating Tempurature Range:
+0.0/+70.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
TEST-PR-OGR-AMSE
Features Provided:
High speed and low power and asynchronous and high performance
Inclosure Material:
Plastic
Inclosure Configuration:
Dual-in-line
Product Name:
Cmos asynchronous fifo
Voltage Rating And Type Per Characteristic:
-0.5 volts input and 7.0 volts input
Time Rating Per Chacteristic:
35.00 nanoseconds af output megawatts
Memory Device Type:
First-in first-out
Special Features:
4096 x 9
Terminal Type And Quantity:
28 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0